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[V40100K-E3/4W](#)

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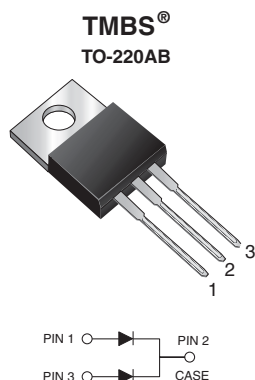


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**V40100K**

Vishay General Semiconductor

## Dual High-Voltage Trench MOS Barrier Schottky Rectifier



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

### FEATURES

- 150 °C high performance Schottky diode
- Very low forward voltage drop
- Optimized  $V_F$  vs.  $I_R$  trade off for high efficiency
- Increased ruggedness for reverse avalanche capability
- Negligible switching losses
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)

### TYPICAL APPLICATIONS

For use in high frequency converters, high efficiency SMPS, output rectification, freewheeling, reverse battery protection, DC/DC system and increased power density systems.

| PRIMARY CHARACTERISTICS                 |                     |
|---|---------------------|
| $I_{F(AV)}$                             | 2 x 20 A            |
| $V_{RRM}$                               | 100 V               |
| $I_{FSM}$                               | 250 A               |
| $V_F$ at $I_F = 20$ A at $T_J = 125$ °C | 0.63 V              |
| $T_J$ max.                              | 150 °C              |
| Package                                 | TO-220AB            |
| Diode variation                         | Dual common cathode |

### MECHANICAL DATA

**Case:** TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

**Marking:** V40100K

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

| MAXIMUM RATINGS ( $T_A = 25$ °C unless otherwise noted)                                      |                |              |            |
|--|----------------|--------------|------------|
| PARAMETER  | SYMBOL         | V40100K      | UNIT       |
| Maximum repetitive peak reverse voltage  | $V_{RRM}$      | 100          | V          |
| Maximum average forward rectified current (fig. 1)   | $I_{F(AV)}$    | total device | 40         |
|  |                | per diode    | 20         |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | $I_{FSM}$      | 250          | A          |
| Non-repetitive avalanche energy at $T_J = 25$ °C, $I_{AS} = 1.5$ A, $L = 60$ mH per diode    | $E_{AS}$       | 67.5         | mJ         |
| Voltage rate of change   | dV/dt          | 10 000       | V/ $\mu$ s |
| Operating junction and storage temperature range   | $T_J, T_{STG}$ | -40 to +150  | °C         |



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| ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted) |                         |                         |                                |                  |      |      |
|--|-------------------------|-------------------------|--------------------------------|------------------|------|------|
| PARAMETER  | TEST CONDITIONS         |                         | SYMBOL                         | TYP.             | MAX. | UNIT |
| Breakdown voltage  | I <sub>R</sub> = 1.0 mA | T <sub>A</sub> = 25 °C  | V <sub>BR</sub> <sup>(2)</sup> | 100<br>(minimum) | -    | V    |
|  | I <sub>R</sub> = 10 mA  |                         |                                | 105<br>(minimum) | -    |      |
| Instantaneous forward voltage per diode                                    | I <sub>F</sub> = 5.0 A  | T <sub>A</sub> = 25 °C  | V <sub>F</sub> <sup>(1)</sup>  | 0.51             | -    | V    |
|  | I <sub>F</sub> = 10 A   |                         |                                | 0.59             | -    |      |
|  | I <sub>F</sub> = 20 A   |                         |                                | 0.72             | 0.82 |      |
|  | I <sub>F</sub> = 5.0 A  | T <sub>A</sub> = 125 °C |                                | 0.44             | -    |      |
|  | I <sub>F</sub> = 10 A   |                         |                                | 0.53             | -    |      |
|  | I <sub>F</sub> = 20 A   |                         |                                | 0.63             | 0.67 |      |
| Reverse current at rated V <sub>R</sub> per diode                          | V <sub>R</sub> = 70 V   | T <sub>A</sub> = 25 °C  | I <sub>R</sub> <sup>(2)</sup>  | 9                | -    | μA   |
|  |                         | T <sub>A</sub> = 100 °C |                                | 10               | -    | mA   |
|  | V <sub>R</sub> = 100 V  | T <sub>A</sub> = 25 °C  |                                | -                | 1000 | μA   |
|  |                         | T <sub>A</sub> = 100 °C |                                | 21               | 45   | mA   |

**Notes**

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width ≤ 40 ms

| THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted) |            |                  |              |      |
|---|------------|------------------|--------------|------|
| PARAMETER   |            | SYMBOL           | V40100-M3/4W | UNIT |
| Maximum junction to case  | per diode  | R <sub>θJC</sub> | 4            | °C/W |
|   | per device |                  | 2            |      |
| Typical thermal resistance case to heatsink                             |            | R <sub>θJS</sub> | 0.5          |      |

| ORDERING INFORMATION (Example) |               |                 |              |               |               |
|--------------------------------|---------------|-----------------|--------------|---------------|---------------|
| PACKAGE                        | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
| TO-220AB                       | V40100K-M3/4W | 1.85            | 4W           | 50/tube       | Tube          |

**RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)**

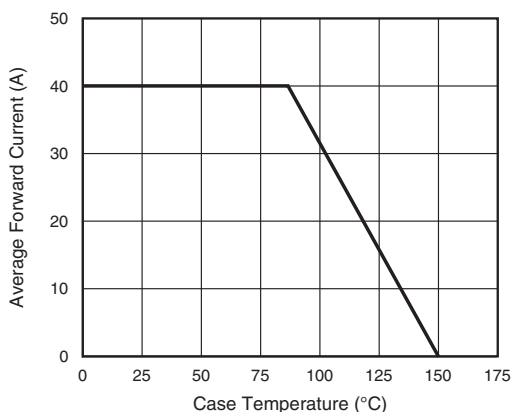


Fig. 1 - Forward Current Derating Curve

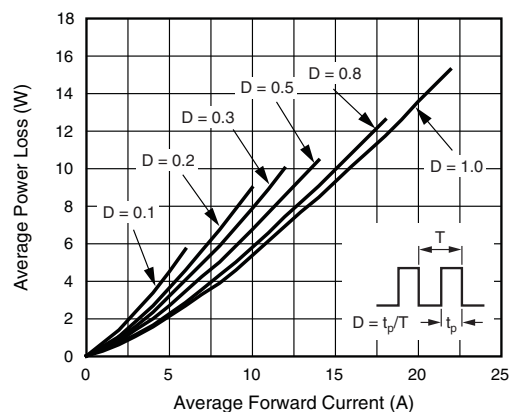


Fig. 2 - Forward Power Loss Characteristics Per Diode



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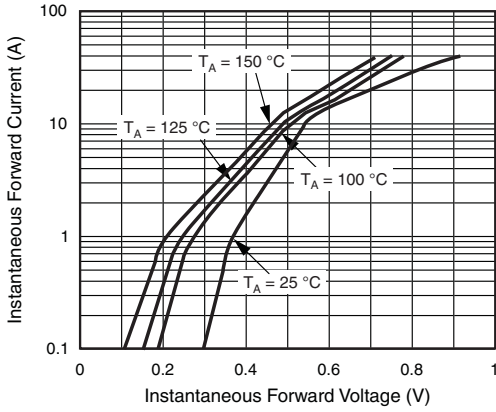


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

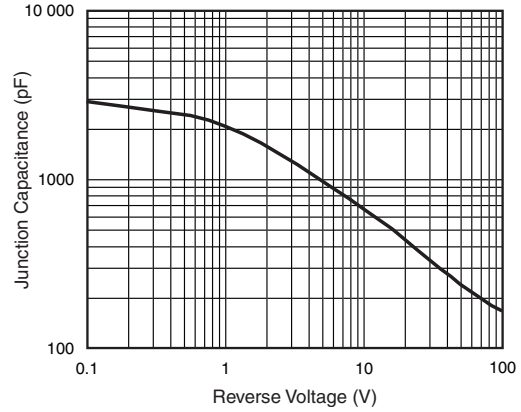


Fig. 5 - Typical Junction Capacitance Per Diode

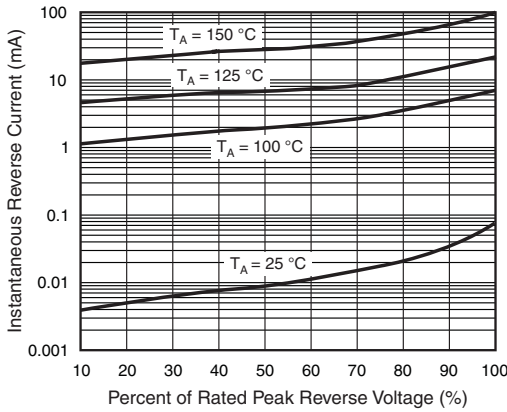


Fig. 4 - Typical Reverse Characteristics Per Diode

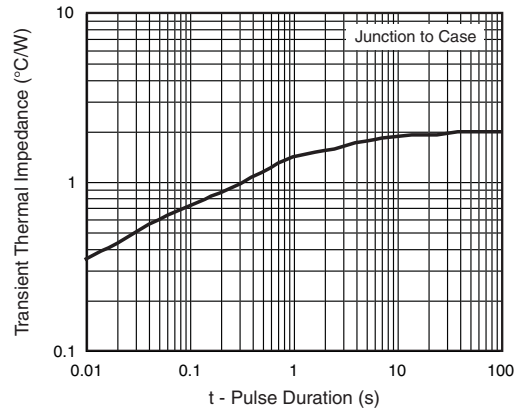
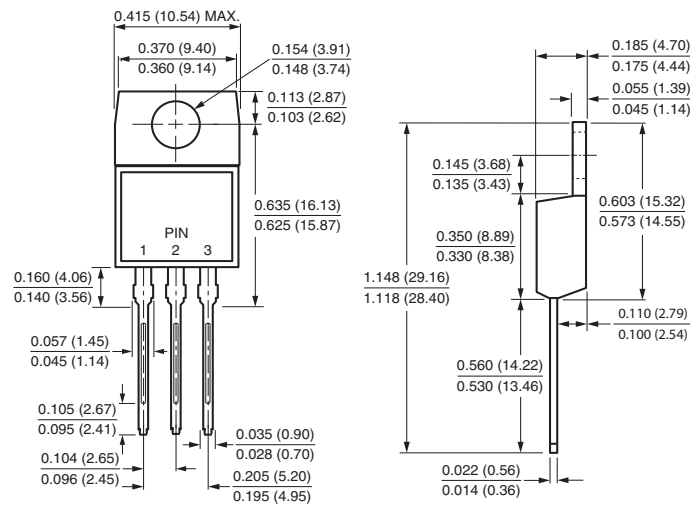


Fig. 6 - Typical Transient Thermal Impedance Per Diode

**PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

**TO-220AB**





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